

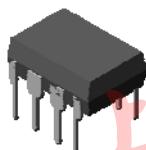


Semiconductor

<http://www.yozo.hk>



SOP-8



DIP-8

## ORDERING INFORMATION

Product	Marking	Package
SN358	SN358	SOP-8
SN358P	SN358P	DIP-8

### ▲ Marking Information



(1) Device Code

(2) Year & Week Code

## Dual Operational Amplifier SN358/P

### Description

The SN358/P consists of two independent high gain

Internally frequency compensated operational amplifiers designed to operate from a single power supply over a wide range of voltage.

### Application

◆ Transducer amplifier

◆ DC gain blocks

◆ Conventional operational amplifiers

### Features and Benefits

◆ Input common mode voltage range includes ground

◆ Internally frequency compensated for unity gain

◆ Large DC voltage gain : 100dB

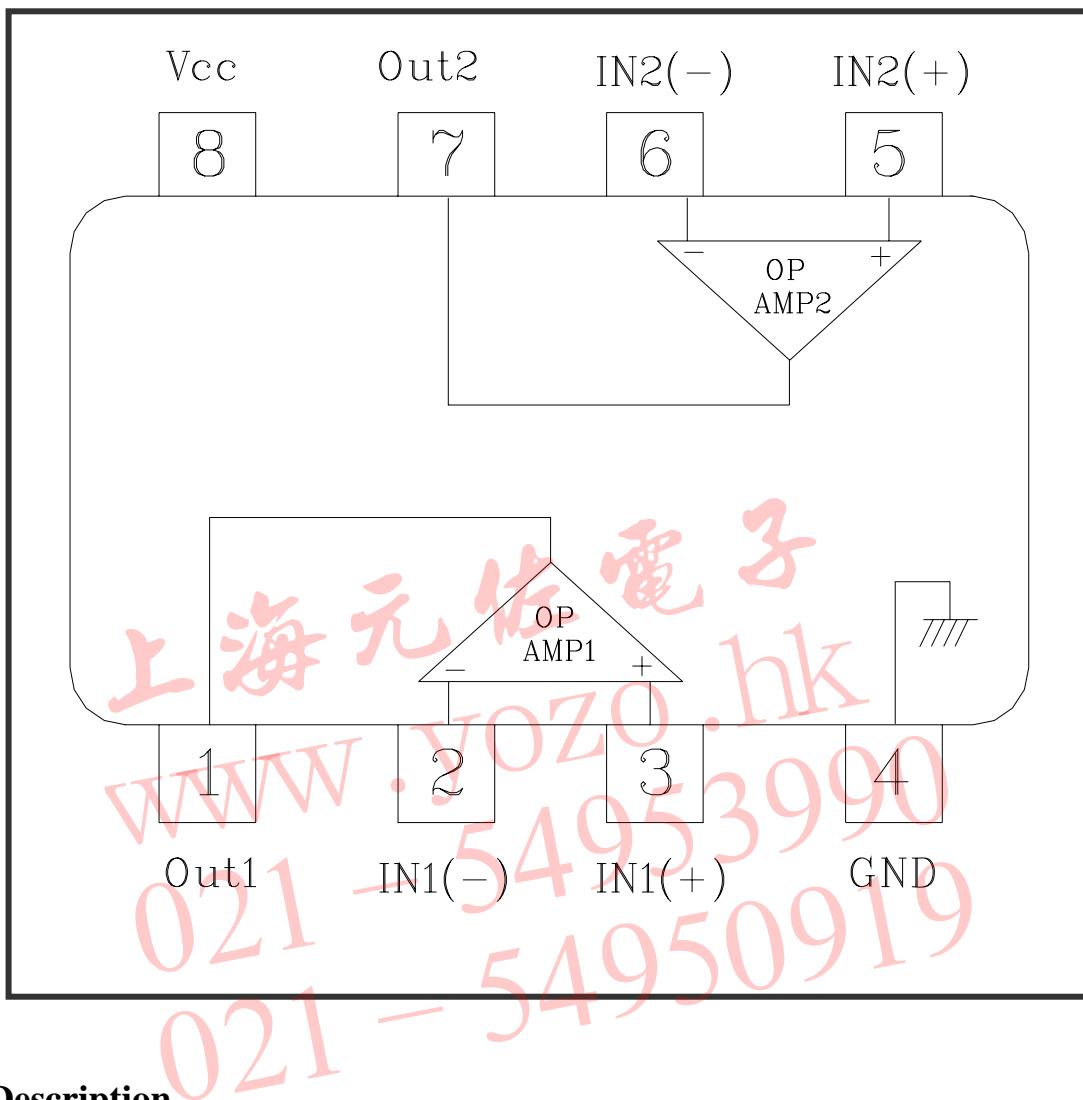
◆ Wide bandwidth for unity gain : 1 MHz

◆ Very low power consumption

◆ Wide supply voltage range :

[ Single : 3V ~ 30V, Dual : ±1.5 ~ ±15V ]

## ◆ Internal Block Diagram



## ◆ Pin Description

No	Symbol	I/O	Description
1	Out1	O	OP-Amp1 Output
2	IN1(-)	I	OP-Amp1's Inverting Input
3	IN1(+)	I	OP-Amp1's Non-inverting Input
4	GND	GND	GND
5	IN2(+)	I	OP-Amp2's Non-inverting Input
6	IN2(-)	I	OP-Amp2's Inverting Input
7	Out2	O	OP-Amp2 Output
8	V <sub>CC</sub>	PWR	V <sub>CC</sub> for Dual Operational Amplifier

## Absolute maximum ratings

Characteristic	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	36 or $\pm 18$	V
Differential input voltage	V <sub>IND</sub>	32	V
Input voltage	V <sub>IN</sub>	-0.3 ~ +32	V
Power Dissipation	P <sub>D</sub>	SOP-8 600	mW
		DIP-8 1000	mW
Operating temperature	T <sub>opr</sub>	-45 ~ +85	°C
Storage temperature	T <sub>stg</sub>	-55 ~ 150	°C

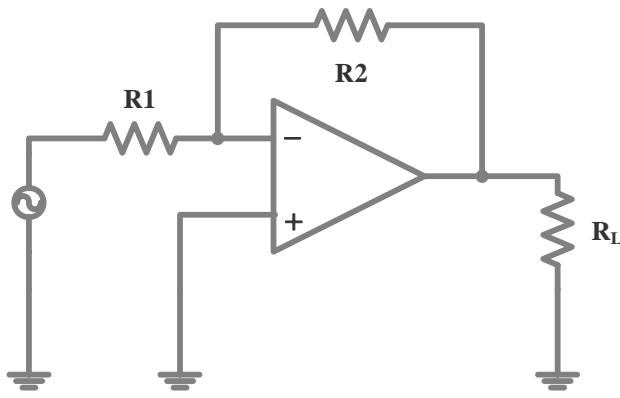
## Electrical Characteristics

(Unless otherwise specified. V<sub>CC</sub> = 5V and -45 °C ≤ Ta ≤ +85 °C)

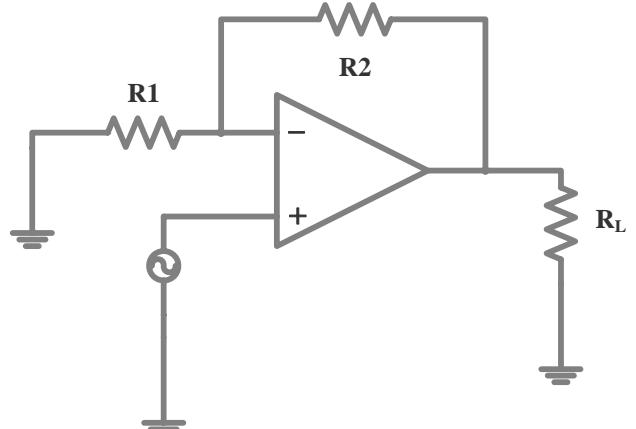
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input offset voltage	V <sub>IOS</sub>	5V ≤ V <sub>CC</sub> ≤ 30V (Ta=25 °C)	-	±2	±7	mV
		R <sub>g</sub> = 0Ω, 0V ≤ V <sub>IC</sub> ≤ V <sub>CC</sub> -1.5V	-	-	±9	
Input offset voltage drift	ΔV <sub>IOS</sub> /ΔT	R <sub>g</sub> = 0Ω	-	7	-	μV/°C
Input offset current	I <sub>IOS</sub>		-	±5	±50	nA
Input offset current drift	ΔI <sub>IOS</sub> /ΔT		-	-	±150	
Input bias current	I <sub>IB</sub>		-	45	250	nA
Input common mode voltage range	V <sub>ICR</sub>	(Ta=25 °C)	-	40	500	
		V <sub>CC</sub> = 30V	0	-	V <sub>CC</sub> -1.5	V
Supply current	I <sub>CC</sub>	V <sub>CC</sub> = 30V, R <sub>L</sub> = ∞	-	1	2	mA
		V <sub>CC</sub> = 5V, R <sub>L</sub> = ∞	-	0.7	1.2	
Large signal voltage gain	G <sub>V</sub>	V <sub>CC</sub> = 15V (Ta=25 °C)	25	100	-	V/mV
		R <sub>L</sub> ≥ 2 KΩ	15	-	-	
Output voltage swing	V <sub>OH</sub>	V <sub>CC</sub> = 30V R <sub>L</sub> = 2 KΩ	26	-	-	V
		R <sub>L</sub> = 10 KΩ	27	28	-	
	V <sub>OL</sub>	V <sub>CC</sub> = 5V, R <sub>L</sub> ≤ 10 KΩ	-	3	20	mV
Common mode rejection ratio	CMRR	(Ta=25 °C)	65	90	-	dB
Power supply rejection ratio	PSRR	(Ta=25 °C)	65	100	-	dB
Output source current	I <sub>O+</sub>	V <sub>CC</sub> = 15V (Ta=25 °C)	20	40	-	mA
		V <sub>IN+</sub> = 1V, V <sub>IN-</sub> = 0V	10	20	-	
Output sink current	I <sub>O-</sub>	V <sub>CC</sub> = 15V (Ta=25 °C)	10	20	-	mA
		V <sub>IN+</sub> = 0V, V <sub>IN-</sub> = 1V	5	8	-	
		V <sub>OUT</sub> = 200mV, (Ta=25 °C)	12	50	-	μA
		V <sub>IN+</sub> = 0V, V <sub>IN-</sub> = 1V				
Output short circuit to ground	I <sub>SC</sub>	Ta=25 °C	-	40	60	mA

## Typical Applications

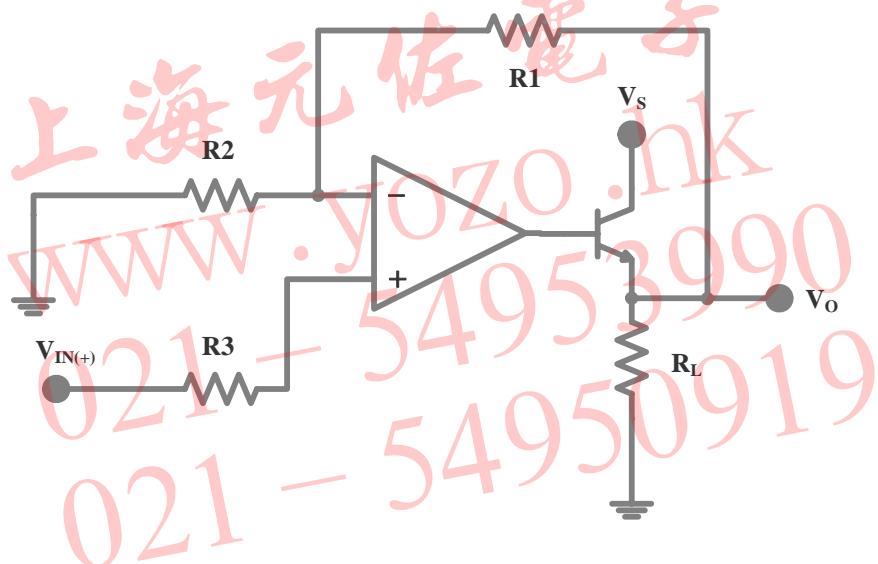
**Inverting Amplifier**



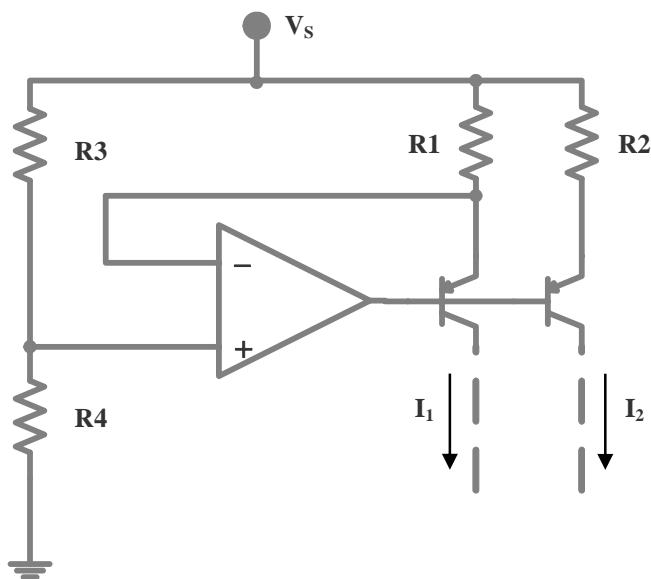
**Non-inverting Amplifier**



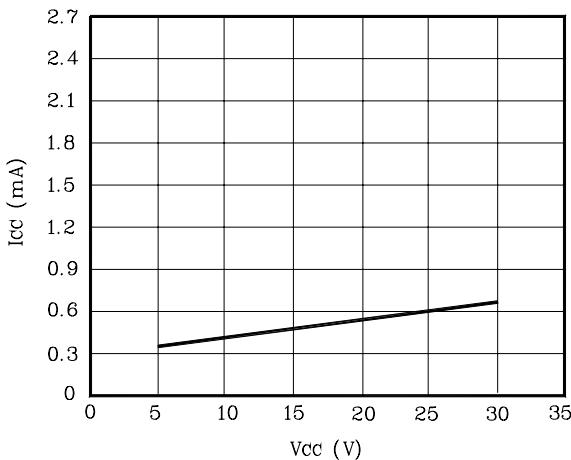
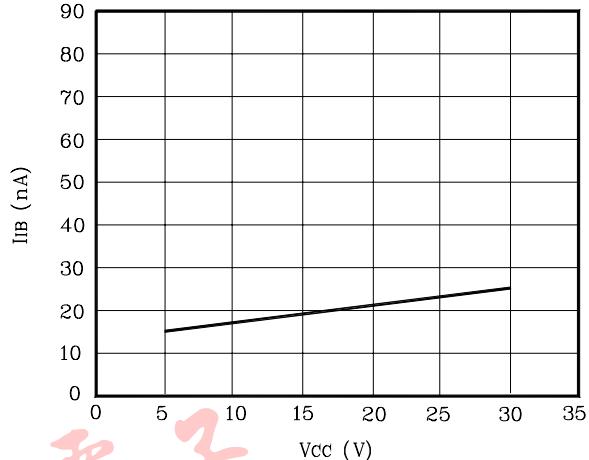
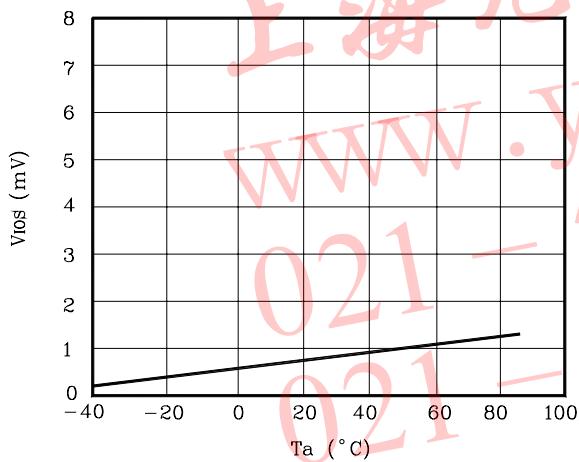
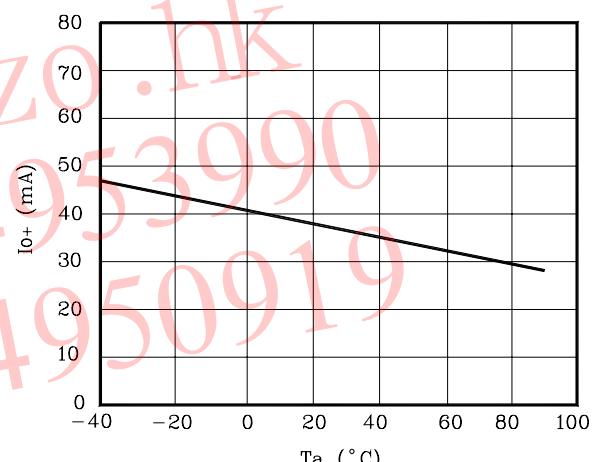
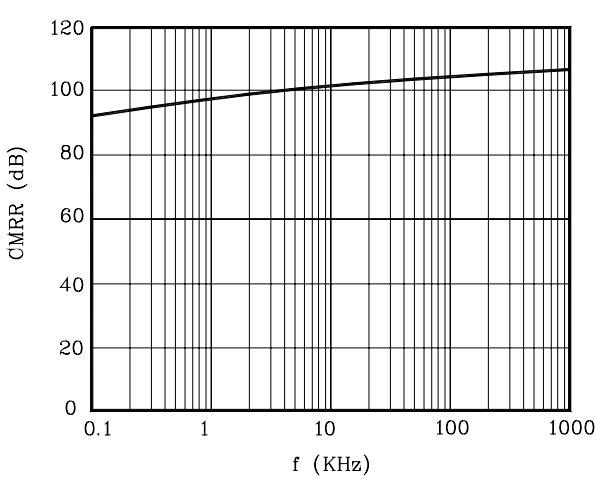
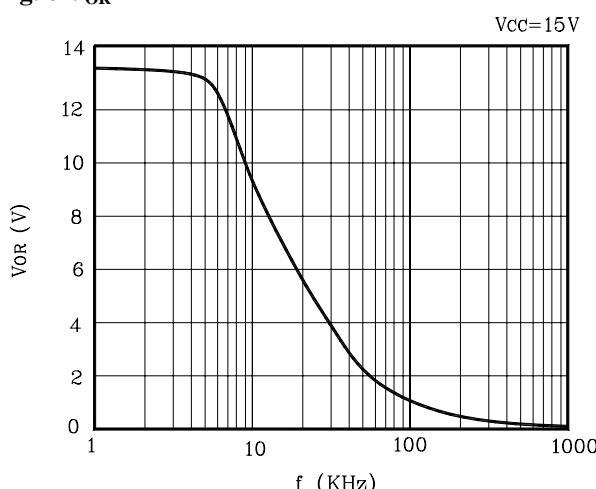
**Power Amplifier**

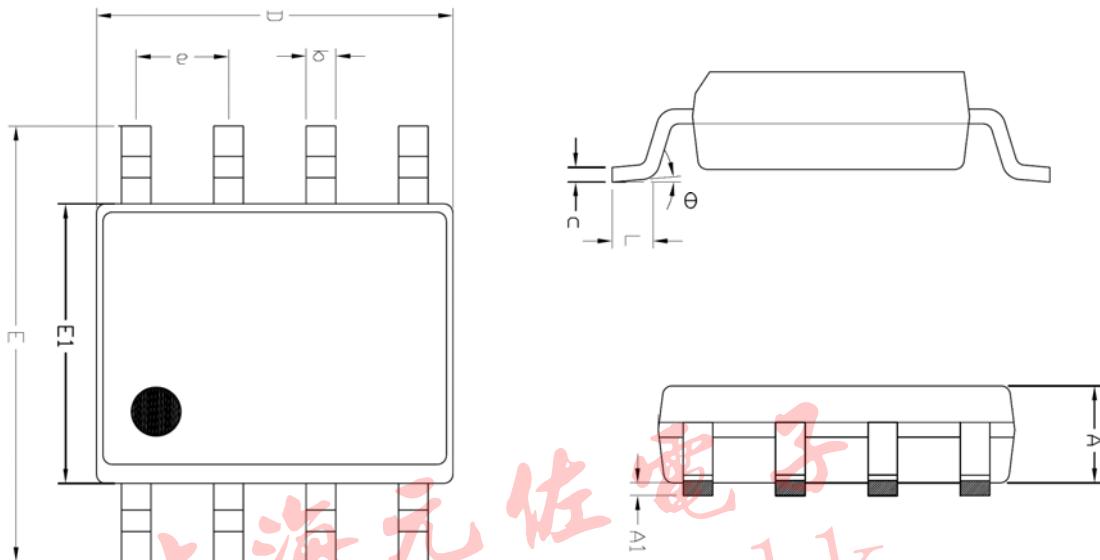


**Fixed Current Sources**

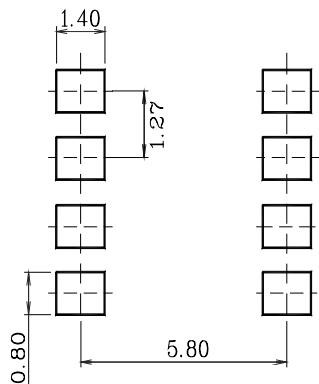


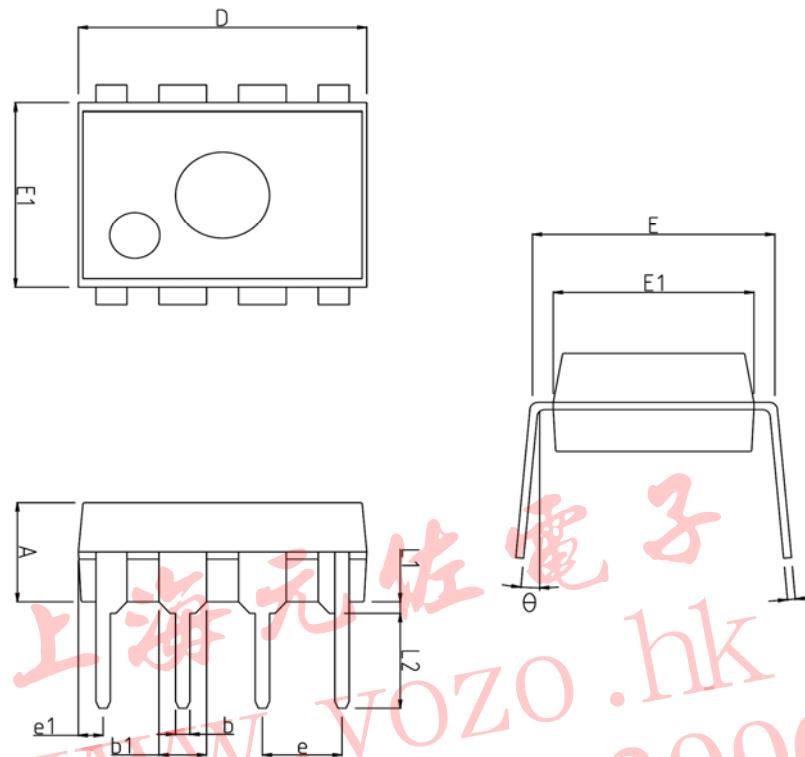
## Electrical Characteristic Curves

**Fig. 1**  $I_{CC}$ - $V_{CC}$ **Fig. 2**  $I_{IB}$ - $V_{CC}$ **Fig. 3**  $V_{IOS}$ - $T_a$ **Fig. 4**  $I_o$ - $T_a$ **Fig. 5** CMRR-f**Fig. 6**  $V_{OR}$ -f

**Outline Dimension (Unit : mm)**


SYMBOL	MILLIMETER(mm)			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	1.245	—	1.445	
A1	0.125	0.175	0.275	
b	0.320	0.420	0.520	
c	0.170	0.220	0.270	
D	4.802	4.902	5.002	
E	5.870	6.020	6.170	
E1	3.761	3.861	3.961	
e	1.270 BSC			
L	0.462	0.562	0.662	
θ	0 °	—	8 °	

**\* Recommend PCB solder land (Unit : mm)**


**Outline Dimension (Unit : mm)**


SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	3.20	3.40	3.60	
b	0.36	0.46	0.56	
b1	1.42	1.52	1.62	
c	0.20	0.25	0.35	
D	9.00	9.20	9.40	
E	7.37	7.62	7.87	
E1	6.20	6.40	6.60	
e	2.54 TYP			
e1	0.79 TYP			
L1	0.33	—	—	
L2	3.00	3.30	3.60	
θ	0°	—	15°	